

MBR160HW SURFACE MOUNT SCHOTTKY BARRIER DIODE



Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-0
- Terminals finish: 100% Pure Tin
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams(approx)

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

| Characteristic | Symbol | MBR160HW | Unit |
|---|-----------------------------------|-------------|------|
| Peak Repetitive Reverse Voltage | V _{RRM} | 60 | V |
| Working Peak Reverse Voltage | V _{RWM} | | |
| DC Blocking Voltage | V _R | | |
| Forward Continuous Current@T _A = 90°C | I _F | 1.0 | A |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load(JEDEC Method) | I _{FSM} | 20 | A |
| Typical Thermal Resistance, Junction to Ambient Air(Note1) | R _{θJA} | 222 | °C/W |
| Junction and Storage Temperature Range | T _J , T _{STG} | -65 to +125 | °C |

| Characteristic | Symbol | Typ. | Max. | Unit |
|--|-----------------|-------|------|------|
| Forward Voltage Drop @I _F =1.0A | V _{FM} | 0.63 | 0.72 | V |
| Peak Reverse Leakage Current @DC Blocking Voltage | I _{RM} | 0.005 | 0.3 | mA |
| Junction Capacitance(V _R =5 DC, f=1MHz) | C _J | 42 | 55 | pF |

Note: 1. Valid provided that terminals are kept at ambient temperature.

Ratings and Characteristics Curves

Figure 1
Typical Forward Characteristics

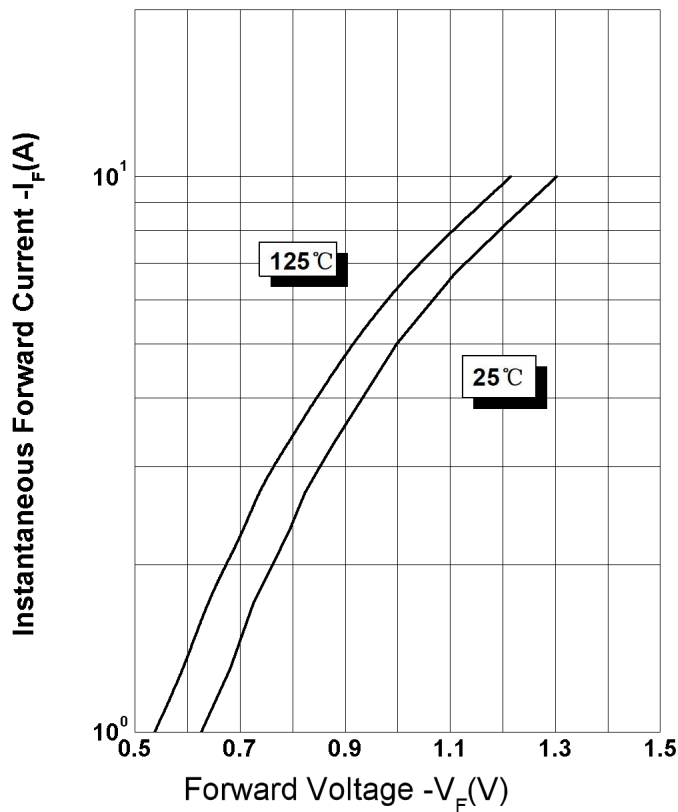


Figure 2
Typical Reverse Characteristics

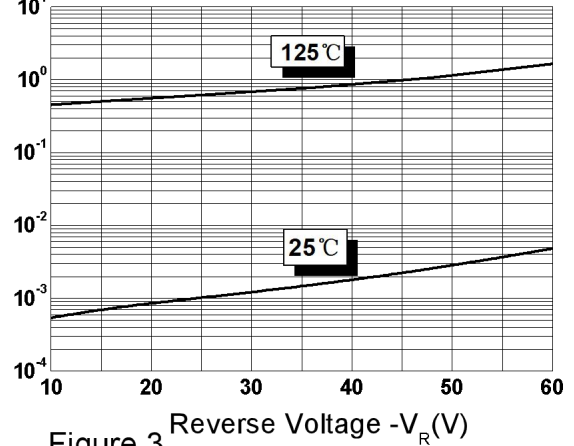
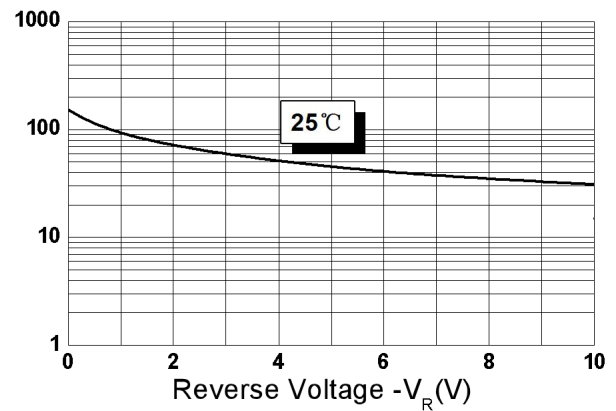
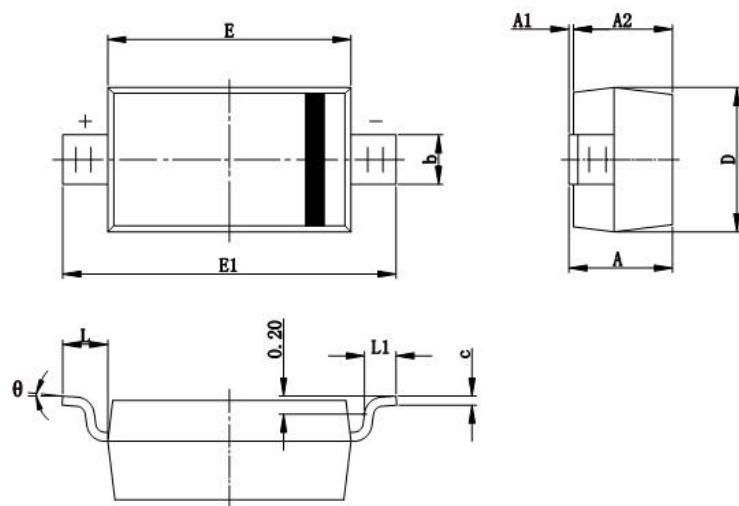


Figure 3
Typical Junction Capacitance



Mechanical Dimensions SOD-123



| SYMBOL | Millimeters | | Inches | |
|----------|-------------|-------|------------|-------|
| | MIN. | MAX. | MIN. | MAX. |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.450 | 0.650 | 0.018 | 0.026 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 1.500 | 1.700 | 0.059 | 0.067 |
| E | 2.600 | 2.800 | 0.102 | 0.110 |
| E1 | 3.550 | 3.850 | 0.140 | 0.152 |
| L | 0.500 REF. | | 0.020 REF. | |
| L1 | 0.250 | 0.450 | 0.010 | 0.018 |
| θ | 0° | 8° | 0° | 8° |

Ordering Information

| Device | Package | Shipping |
|------------|-------------------|----------------|
| MBR160HW | SOD-123 (Pb-Free) | 3000pcs / reel |
| MBR160HWTR | SOD-123 (Pb-Free) | 3000pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

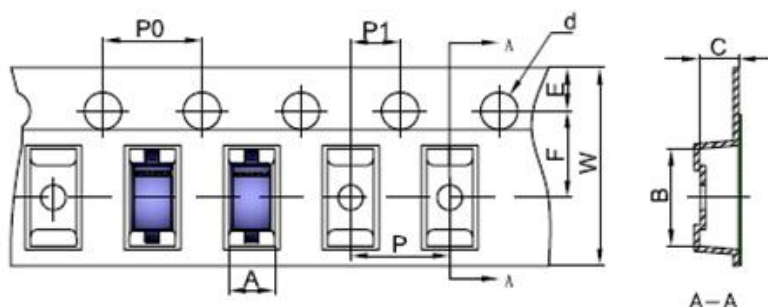


Where X is Date Code

L16 = Part Name

Notes: Date code is after 1828,
This part mark data code.

Carrier Tape Specification SOD-123



| SYMBOL | Millimeters | |
|--------|-------------|------|
| | Min. | Max. |
| A | 1.80 | 1.90 |
| B | 3.89 | 3.99 |
| C | 1.52 | 1.62 |
| d | 1.45 | 1.65 |
| E | 1.65 | 1.85 |
| F | 3.40 | 3.60 |
| P | 3.90 | 4.10 |
| P0 | 3.90 | 4.10 |
| P1 | 1.90 | 2.10 |
| W | 7.90 | 8.30 |

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